



Production V1 23 Aug 11

Features

- GaN depletion mode HEMT microwave transistor
- Common source configuration
- Broadband Class AB operation
- Thermally enhanced Cu/Mo/Cu package
- RoHS Compliant
- +50V Typical Operation
- MTTF of 114 years (Channel Temperature < 200°C)

Application

• Civilian and Military Pulsed Radar



Product Description

The MAGX-002731-100L00 is a gold metalized matched Gallium Nitride (GaN) on Silicon Carbide RF power transistor optimized for civilian and military radar pulsed applications between 2700 - 3100 MHz. Using state of the art wafer fabrication processes, these high performance transistors provide high gain, efficiency, bandwidth, ruggedness over a wide bandwidth for today's demanding application needs. The MAGX-002731-100L00 is constructed using a thermally enhanced Cu/Mo/Cu flanged ceramic package which provides excellent thermal performance. High breakdown voltages allow for reliable and stable operation in extreme mismatched load conditions unparalleled with older semiconductor technologies.

Typical RF Performance

Freq. (MHz)	Pin (W	Pout (W Peak)	Gain (dB)	ld-Pk (A)	Eff (%)
2700	7	109	12	4.2	51
2900	7	112	12	4.4	51
3100	7	109	12	4.2	52

Typical RF performance measured in M/A-COM RF test fixture. Devices tested in common source Class-AB configuration as follows: Vdd=50V, Idq=500mA (pulsed), F=2.7—3.1 GHz, Pulse=500us, Duty=10%.

Ordering Information

MAGX-002731-100L00 MAGX-002731-SB2PPR 100W GaN Power Transistor Evaluation Fixture

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GaN HEMT Pulsed Power Transistor	
2.7 - 3.1 GHz, 100W Peak, 500us Pulse, 10% Duty Cycle	

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Absolute Maximum Ratings Table (1, 2, 3	3)
Supply Voltage (Vdd)	+65V
Supply Voltage (Vgg)	-8 to 0V
Supply Current (Id1)	7100 mA Pk
Input Power (Pin)	+34 dBm
Absolute Max. Junction/Channel Temp	200 °C
Pulsed Power Dissipation (Pavg) at 85 °C	128W
Thermal Resistance, (Tchannel = 200 °C) V _{DD} = 50V, I _{DQ} = 500mA, Pout = 100W Peak (300us Pulse / 10% Duty)	0.9 °C/W
Operating Temp	-40 to +95C
Storage Temp	-65 to +150C
Mounting Temperature	See solder reflow profile
ESD Min Machine Model (MM)	50 V
ESD Min Human Body Model (HBM)	>250 V
MSL Level	MSL1

(1) Operation of this device above any one of these parameters may cause permanent damage.

(2) Channel temperature directly affects a device's MTTF. Channel temperature should be kept as low as possible to maximize lifetime.

(3) For saturated performance it recommended that the sum of (3*Vdd + abs(Vgg)) <175

Parameter	Test Conditions	Symbol	Min	Тур	Max	Units
DC CHARACTERISTICS						
Drain-Source Leakage Current	V _{GS} = -8V, V _{DS} = 175V	I _{DS}	-	-	6	mA
Gate Threshold Voltage	$V_{DS} = 5V, I_D = 15.0 \text{mA}$	V _{GS (th)}	-5	-3	-2	V
Forward Transconductance	$V_{DS} = 5V, I_{D} = 3.5 mA$	G _M	2.5	-	-	S
DYNAMIC CHARACTERISTICS						
Input Capacitance	Not applicable—Input internally matched	C _{GS}	N/A	N/A	N/A	pF
Output Capacitance	V_{DS} = 50V, V_{GS} = -8V, F = 1MHz	C _{DS}	-	30.3	35.4	pF
Feedback Capacitance	$V_{DS} = 50V, V_{GS} = -8V, F = 1MHz$	C_{GD}	-	2.8	5.4	pF

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Electrical Specifications: $T_c = 25 \pm 5^{\circ}C$ (Room Ambient)

Parameter	Test Conditions	Symbol	Min	Тур	Max	Units	
RF FUNCTIONAL TESTS Vdd=50V, Idq=500mA (pulsed), F=2.7—3.1 GHz, Pulse=500us, Duty=10%							
Output Power	Pin = 7W Peak	P _{OUT}	100 10	105 10.5	-	W Peak W Ave	
Power Gain	Pout = 100W Peak, 10W Ave	G _P	11.6	12.6	-	dB	
Drain Efficiency	Pin = 7W Peak	$\eta_{\rm D}$	47	53	-	%	
Load Mismatch Stability	Pin = 7W Peak	VSWR-S	5:1	-	-	-	
Load Mismatch Tolerance	Pin = 7W Peak	VSWR-T	10:1	-	-	-	

Test Fixture Impedance

F (MHz)	Z _{IF} (Ω)	Z _{OF} (Ω)
2700	3.5 - j7.5	3.4 + j0.4
2900	2.7 - j5.3	4.7 - j0.8
3100	2.0 - j4.1	2.5 - j1.7



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RF Power Transfer Curve at 50V Drain Bias, Idq=0.5A Output Power vs. Input Power



Gain vs. Frequency 50V Drain Bias, Idq=0.5A

Return Loss vs. Frequency 50V Drain Bias, Idq=0.5A



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RF Power Transfer Curve at 65V Drain Bias, Idq=0.5A Output Power vs. Input Power



Gain vs. Frequency 65V Drain Bias, Idg=0.5A



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Test Fixture Circuit Dimensions







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Outline Drawings





Unless otherwise noted, tolerances are inches ±.005" [millimeters ±0.13mm]

CORRECT DEVICE SEQUENCING

TURNING THE DEVICE ON

- 1. Set V_{GS} to the pinch-off (V_P), typically -5V
- 2. Turn on V_{DS} to nominal voltage (50V)
- 3. Increase V_{GS} until the I_{DS} current is reached
- 4. Apply RF power to desired level

TURNING THE DEVICE OFF

- 1. Turn the RF power off
- 2. Decrease V_{GS} down to V_{P}
- 3. Decrease V_{DS} down to 0V
- 4. Turn off V_{GS}

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